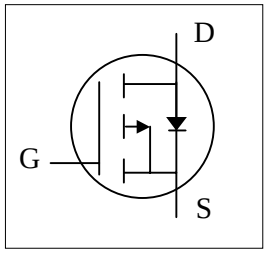
AP6679BGP-HF

Halogen-Free Product

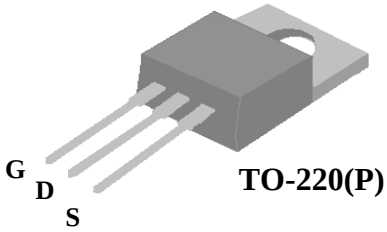
Advanced Power Electronics Corp.

P-CHANNEL ENHANCEMENT MODE POWER MOSFET

- ▼ **Low On-resistance**
- ▼ **Simple Drive Requirement**
- ▼ **Fast Switching Characteristic**
- ▼ **RoHS Compliant & Halogen-Free**



BV_{DSS}	-30V
$R_{DS(ON)}$	9mΩ
I_D	-63A



TO-220(P)

Description

Advanced Power MOSFETs from APEC provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness.

The TO-220 package is widely preferred for commercial-industrial power applications and suited for low voltage applications such as DC/DC converters.

Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	-30	V
V_{GS}	Gate-Source Voltage	±20	V
I_D@T_C=25℃	Continuous Drain Current, V_{GS} @ 10V	-63	A
I_D@T_C=100℃	Continuous Drain Current, V_{GS} @ 10V	-40	A
I_{DM}	Pulsed Drain Current[1]	-240	A
P_D@T_C=25℃	Total Power Dissipation	54.3	W
P_D@T_A=25℃	Total Power Dissipation	2	W
T_{STG}	Storage Temperature Range	-55 to 150	℃
T_J	Operating Junction Temperature Range	-55 to 150	℃

Thermal Data

Symbol	Parameter	Value	Units
Rthj-c	Maximum Thermal Resistance Junction-case	2.3	℃/W
Rthj-a	Maximum Thermal Resistance, Junction-ambient	62	℃/W

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Electrical Characteristics@T_j=25°C(unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS}=0V, I_D=-250uA	-30	-	-	V
$R_{DS(ON)}$	Static Drain-Source On-Resistance[2]	V_{GS}=-10V, I_D=-40A	-	-	9	mΩ
		V_{GS}=-4.5V, I_D=-30A	-	-	15	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS}=V_{GS}, I_D=-250uA	-1	-	-3	V
g_{fs}	Forward Transconductance	V_{DS}=-10V, I_D=-30A	-	60	-	S
I_{DSS}	Drain-Source Leakage Current	V_{DS}=-24V, V_{GS}=0V	-	-	-10	uA
I_{GSS}	Gate-Source Leakage	V_{GS}= ±20V, V_{DS}=0V	-	-	±100	nA
Q_g	Total Gate Charge[2]	I_D=-30A	-	44	70	nC
Q_{gs}	Gate-Source Charge	V_{DS}=-24V	-	6.5	-	nC
Q_{gd}	Gate-Drain ("Miller") Charge	V_{GS}=-4.5V	-	28.5	-	nC
$t_{d(on)}$	Turn-on Delay Time[2]	V_{DS}=-15V	-	11	-	ns
t_r	Rise Time	I_D=-30A	-	67	-	ns
$t_{d(off)}$	Turn-off Delay Time	R_G=1Ω	-	37	-	ns
t_f	Fall Time	V_{GS}=-10V	-	22	-	ns
C_{iss}	Input Capacitance	V_{GS}=0V	-	3500	5600	pF
C_{oss}	Output Capacitance	V_{DS}=-25V	-	520	-	pF
C_{rss}	Reverse Transfer Capacitance	f=1.0MHz	-	495	-	pF
R_g	Gate Resistance	f=1.0MHz	-	2	-	Ω

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V_{SD}	Forward On Voltage[2]	I_S=-30A, V_{GS}=0V	-	-	-1.2	V
t_{rr}	Reverse Recovery Time[2]	I_S=-10A, V_{GS}=0V,	-	34	-	ns
Q_{rr}	Reverse Recovery Charge	dI/dt=100A/μs	-	30	-	nC

Notes:

1.Pulse width limited by Max. junction temperature.

2.Pulse test

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.
USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.
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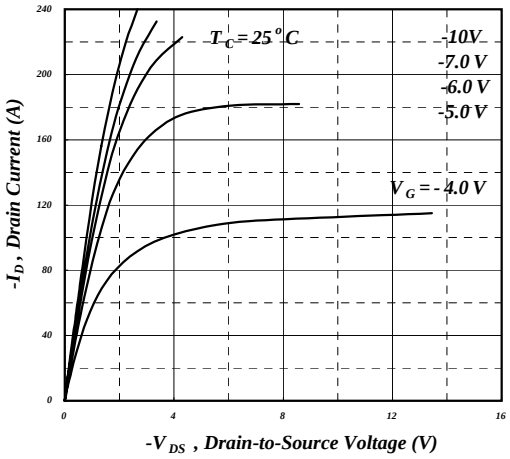

Fig 1. Typical Output Characteristics

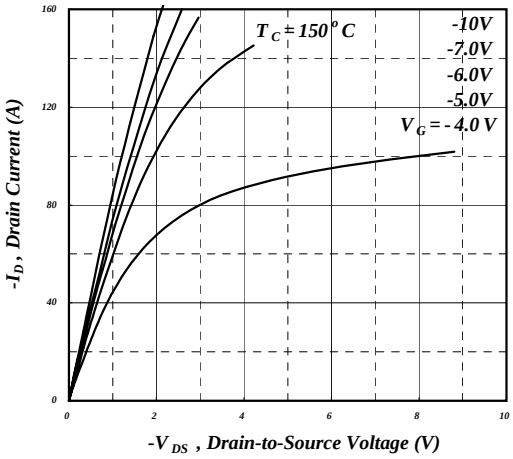

Fig 2. Typical Output Characteristics

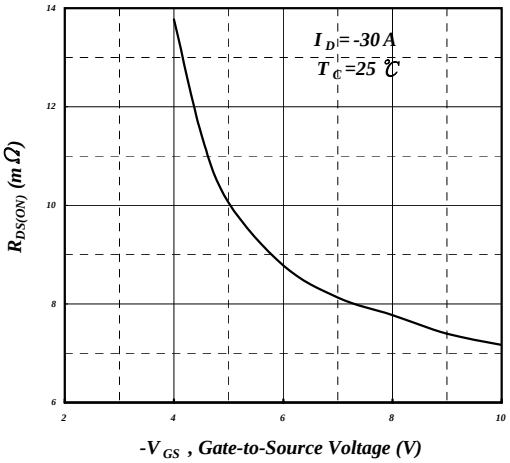

Fig 3. On-Resistance v.s. Gate Voltage

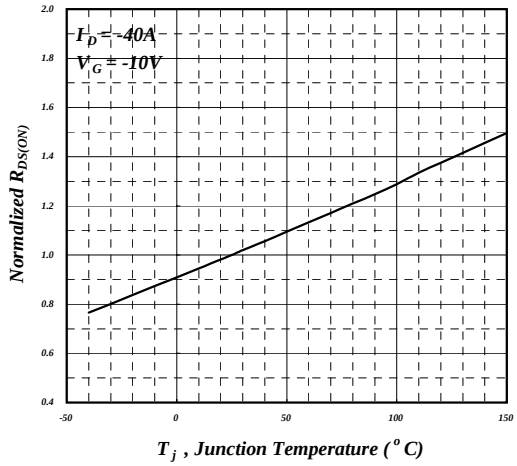

Fig 4. Normalized On-Resistance v.s. Junction Temperature

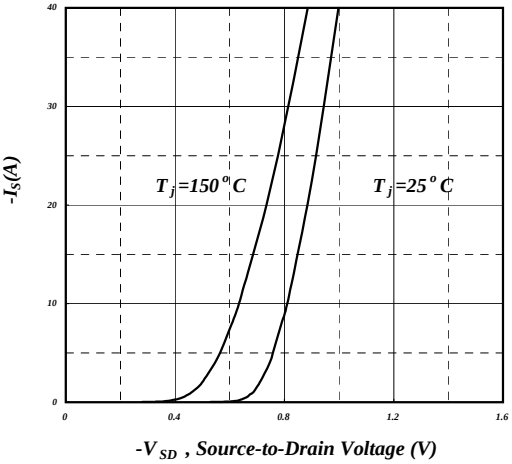

Fig 5. Forward Characteristic of Reverse Diode

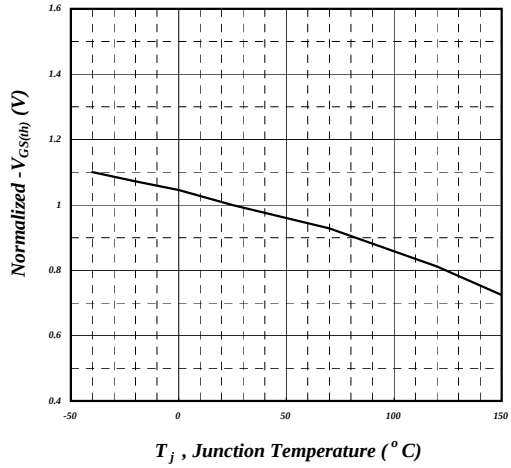

Fig 6. Gate Threshold Voltage v.s. Junction Temperature

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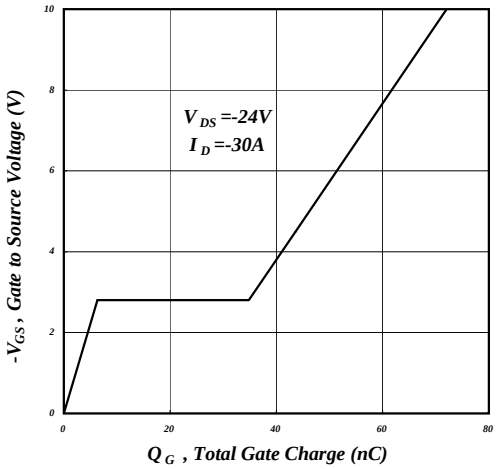

Fig 7. Gate Charge Characteristics

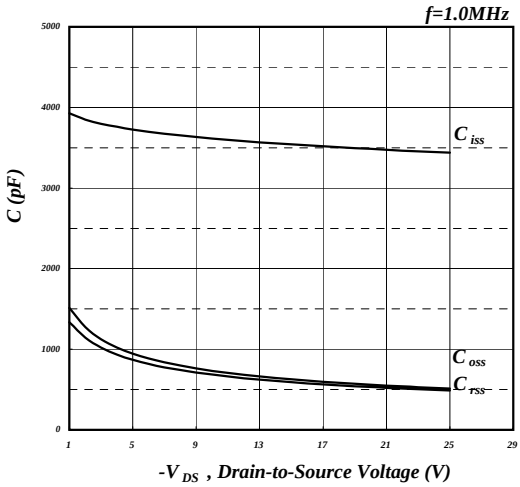

Fig 8. Typical Capacitance Characteristics

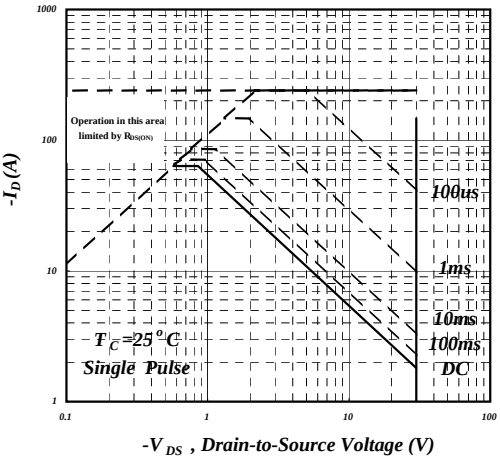

Fig 9. Maximum Safe Operating Area

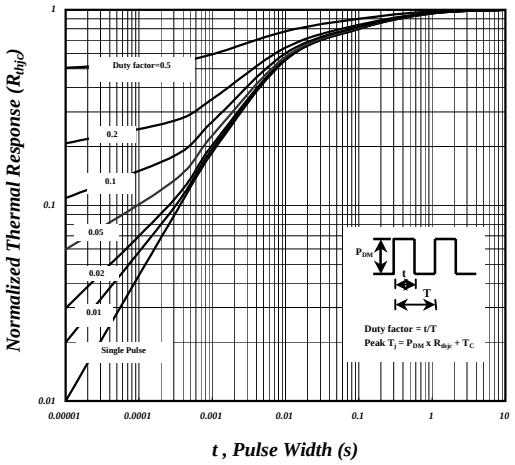

Fig 10. Effective Transient Thermal Impedance

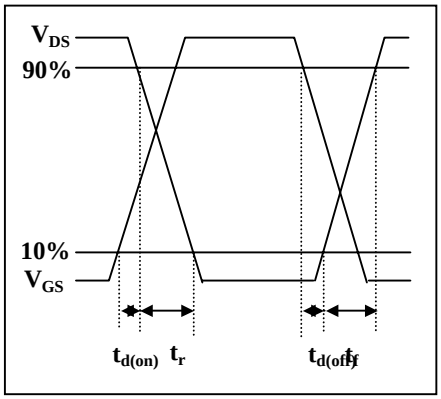

Fig 11. Switching Time Waveform

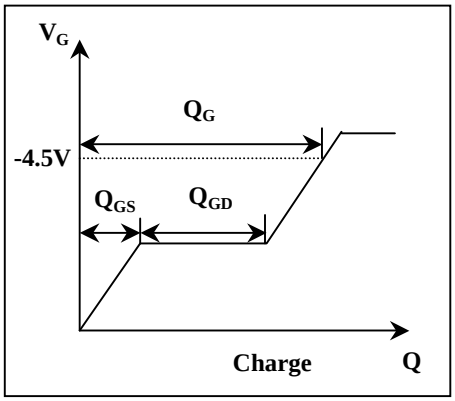

Fig 12. Gate Charge Waveform

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